In the Claims

1	1. (Currently amended) A method for removing contaminate particulate matter from a
2	contaminate particle containing integrated circuit semiconductor substrate surface
3	comprising the steps of:
4	applying a sacrificial coating of a material-curable polymer to a-an integrated circuit
5	semiconductor substrate surface containing undesirable particulate matter thereon,
6	which curable polymer material is to encapsulate and suspend the undesirable
7	particles therein;
8	fluidizing the material-curable polymer if necessary;
9	applying energy to the coated substrate to dislodge at least some of the particulate
10	matter from the surface of the integrated circuit semiconductor substrate into the
11	fluid curable polymer sacrificial coating such that the particulate matter is partially
12	or fully encapsulated and suspended within the <u>curable polymer</u> sacrificial coating
13	forming a particulate matter containing curable polymer sacrificial material
14	coating;
15	forming curing the fluidized particulate matter containing curable polymer sacrificial
16	material coating to form a cured polymer into a strippable film; and
1 <i>7</i>	removing the particulate matter containing cured polymer sacrificial material coating
18	strippable film from the substrate surface as a strippable film providing a substrate
19	surface having less particulate matter thereon.

•	۷.	(original) The method of claim 1 wherein the substrate is a semiconductor water.
1	3.	(Currently amended) The method of claim 1 wherein the sacrificial coating
2	mater	ial-curable polymer is a fluid.
1	4.	(original) The method of claim 1 wherein the energy used is sonic energy.
1	5.	(original) The method of claim 1 wherein the energy used is thermal, centrifugal,
2	magne	etic or vibrational.
l	6.	(Currently amended) The method of claim 1 wherein the sacrificial coating
2	materi	ial <u>curable polymer</u> is a liquid.
I	7.	(canceled)
l	89.	(canceled)
I	10.	(canceled)
l	1125	5. (Canceled)

- 1 26. (Currently amended) The method of claim 1 wherein the <u>cured polymer strippable</u>
- 2 film is formed simultaneously with application of the energy to dislodge the particles.